Vishay Semiconductors

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High Performance Schottky Rectifier, 1 A



Cathode	Anode
0	 o

DO-214AC (SMA)

PRODUCT SUMMARY				
Package	DO-214AC (SMA)			
I _{F(AV)}	1 A			
V _R	40 V			
V _F at I _F	0.49 V			
I _{RM}	26 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	3.0 mJ			

FEATURES

• Low forward voltage drop



RoHS

COMPLIANT

- Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBRA140TRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES					
I _{F(AV)}	Rectangular waveform	1	A				
V _{RRM}		40	V				
I _{FSM}	t _p = 5 μs sine	120	А				
V _F	1.5 A _{pk} , T _J = 125 °C	0.56	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRA140TRPBF	UNITS	
Maximum DC reverse voltage	V _R	40	V	
Maximum working peak reverse voltage	V _{RWM}	40	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current		50 % duty cycle at T_L = 123 °C, n On PC board 9 mm ² island (0.013 mm thick copper pad area	C C	1.5	А
See fig. 4		50 % duty cycle at T_L = 132 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1	A
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	30	~
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s1.0Frequency limited by T _J maximum V _A = 1.5 x V _R typical1.0		А	

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VS-MBRA140TRPbF



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		1 A	T _{.1} = 25 °C	0.54	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1.5 A	1j=25 0	0.62	
See fig. 1	VFM (*)	1 A	T - 125 °C	0.49	
		1.5 A	T _J = 125 °C	0.56	
Maximum reverse leakage current		T _J = 25 °C	V _R = Rated V _R	0.5	mA
See fig. 2	I _{RM}	T _J = 125 °C		26	
Threshold voltage	V _{F(TO)}	T T monimum		0.36	V
Forward slope resistance	r _t	$T_J = T_J maximum$ 104		mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}, T_J = 25 \text{ °C}, \text{ test signal} = 1 \text{ MHz}$ 38		pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{(1)}$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approximate weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (similar D-64)	1	F	

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink





Fig. 1 - Maximum Forward Voltage Drop Characteristics





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Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

Device code	VS-	MBR	Α	1	40	TR	PbF
		2	3	4	5	6	7
	1		nay Sem			oduct	
	 2 - Schottky MBR series 3 - A = SMA 						
	4	Cur	rent rati	ng (1 = ⁻	1A)		
	5 -	· Volt	age rati	ng (40 =	= 40 V)		
	6	TR	= tape a	and reel	(7500 p	ocs)	
	7	PbF	= term	inations	lead (F	b)-free	

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-MBRA140TRPbF	5AT	7500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95400</u>				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?96008			



Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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